NSN 5962-01-501-6907

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and monolithic and compatible cmos and erasable and programmable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Product Name:

Microcircuit, memory, digital, cmos, uv eraseable programmable logic array, monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Time Rating Per Chacteristic:

30.00 nanoseconds af output megawatts

Memory Device Type:

Pal

Special Features:

Generic p/n v2500bql/lid shall be transparent tp permit ultraviolet light erasure

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

40 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0